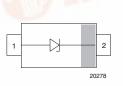


Vishay Semiconductors

Single ESD-Protection Diode in SOD-523





MARKING (example only)



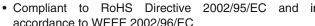
Bar = cathode marking

X = date code

Y = type code (see table below)

FEATURES

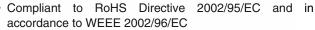
- Single-line ESD-protection
- Capacitance typical C_D = 12 pF $(V_R = 2.5 \text{ V}, f = 1 \text{ MHz})$
- Leakage current I_R < 1 μA (V_R = 5 V)
- ESD-protection acc. IEC 61000-4-2 ± 20 kV contact discharge ± 30 kV air discharge
- e3 Sn







RoHS COMPLIANT GREEN (5-2008)**



| ORDERING INFORMATION | | | | | |
|----------------------|--------------------|--|------------------------|--|--|
| DEVICE NAME | ORDERING CODE | TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL) | MINIMUM ORDER QUANTITY | | |
| VESD05A1B-02V | VESD05A1B-02V-G-08 | 3000 | 3000 | | |

| PACKAGE DATA | | | | | | |
|---------------|-----------------|--------------|--------|--------------------------------------|--------------------------------------|--------------------------|
| DEVICE NAME | PACKAGE NAME | TYPE CODE | WEIGHT | MOLDING COMPOUND FLAMMABILITY RATING | MOISTURE SENSITIVITY LEVEL | SOLDERING CONDITIONS |
| VESD05A1B-02V | SOD-523 | . Н | 1.4 mg | UL 94 V-0 | MSL level 1 (according J-STD-020) | 260 °C/10 s at terminals |

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--------------------------|---|------------------|---------------|------|--|--|
| PARAMETER | TEST CONDITIONS | SYMBOL | VALUE | UNIT | | |
| Peak pulse current | acc. IEC 61000-4-5, 8/20 μs/single shot | I _{PPM} | 3 | Α | | |
| Peak pulse power | acc. IEC 61000-4-5, 8/20 μs/single shot | P _{PP} | 33 | W | | |
| ESD immunity | Contact discharge acc. IEC 61000-4-2; 10 pulses | V_{ESD} | ± 20 | kV | | |
| | Air discharge acc. IEC 61000-4-2; 10 pulses | V ESD | ± 30 | kV | | |
| Operating temperature | Junction temperature | TJ | - 40 to + 125 | °C | | |
| Storage temperature | # III | T _{stg} | - 55 to + 150 | °C | | |



VESD05A1B-02V

Vienay/Semiconductokoo商 Single ESD-Protection Diode in SOD-523



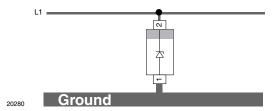
BiAs-MODE (bidirectional asymmetrical protection mode)

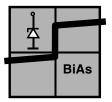
With the VESD05A1B-02V one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 2 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage (V_{RWM}) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch.

As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The clamping voltage (V_C) is defined by the breakthrough voltage (V_{BR}) level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage (V_F) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the VESD05A1B-02V clamping behaviour is bidirectional and asymmetrical (BiAs).





| ELECTRICAL CHARACTERISTICS VESD05A1B-02V | | | | | | | |
|--|---|----------------------|------|------|------|-------|--|
| PARAMETER | TEST CONDITIONS/REMARKS | SYMBOL | MIN. | TYP. | MAX. | UNIT | |
| Protection paths | Number of lines which can be protected | N _{channel} | - | - | 1 | lines | |
| Reverse working voltage | at I _R = 1 μA | V_{RWM} | 5 | - | - | V | |
| Reverse current | at V _R = 5 V | I _R | - | 0.01 | 0.1 | μΑ | |
| Reverse breakdown voltage | at I _R = 1 mA | V_{BR} | 6 | 6.8 | 7.5 | V | |
| Reverse clamping voltage | at I _{PP} = 1 A | V | - | 8 | 9.5 | V | |
| | at I _{PP} = I _{PPM} = 3 A | V _C | - | 8.9 | 11 | V | |
| Forward clamping voltage | at I _{PP} = 0.2 A | | - | 0.95 | 1.2 | V | |
| | at I _{PP} = 1 A | V_{F} | - | 1.3 | - | V | |
| | at I _{PP} = I _{PPM} = 3 A | | - | 1.9 | - | V | |
| Capacitance | at V _R = 0 V; f = 1 MHz | | - | 19 | 23 | pF | |
| | at V _R = 2.5 V; f = 1 MHz | - C _D | - | 12 | - | pF | |

Note

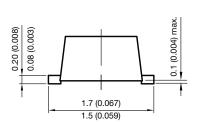
Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 1 and pin 2).

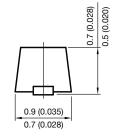
Document Number: 83368 Rev. 1.0, 08-Nov-10

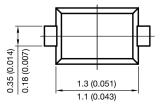
Single ESD-Protection Diode in SOD-523

Vishay Semiconductors

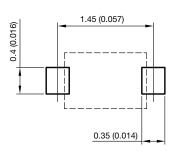
PACKAGE DIMENSIONS in millimeters (inches): SOD-523







foot print recommendation:



Document no.: S8-V-3880.02-001 (4)

Rev. h - Date: 13. Oct. 2010

16864



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 Revision: 18-Jul-08 www.vishay.com